Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1296	358/482	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:01
S2	572	358/482.ccls.	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:01
S3	0	358/482 and transistor and common adj well and semiconductor	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:02
S4	0	358/482 and transistor and (common adj well) and semiconductor	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:02
S5	295	transistor and (common adj well) and semiconductor	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:02
S6	65	transistor and (common adj well) and semiconductor and solid-state	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:02
S7	56	transistor and (common adj well) and semiconductor and solid-state and source and drain	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 12:02
S8	3	transistor and (common adj well) and semiconductor and solid-state and source and drain and photoelectric	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 14:59
S9	3605802	plurality of elements with divid$3	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:03
S10	13618	plurality with elements with divid$3	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:06
S11	1063	plurality with elements with divid$3 same array	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:06

S12	37	plurality with elements with divid$3 same array same interval	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:36
S13	9	picture adj elements with divid$3 same array same interval	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:18
S14	0	picture adj elements with divid$3 same array same interval same contact	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:18
S15	0	power same wiring same interval same array same (shielding with layer) same window same light	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:37
S16	0	power same wiring same interval same array same (shielding layer) same window same light	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:37
S17	0	power same wiring same interval same array same (shielding layer) same window near light	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:37
S18	0	power same wiring same interval same array and (shielding layer) same window near light	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:37
S19	5	power and wiring and interval and array and (shielding layer) same window near light	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:38
S20	41	power and wiring and interval and array and (shielding layer) and window near light	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:39
S21	0	power and wiring and interval and array and (shielding layer) and window near light and "358"/$.ccls.	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:38
S22	11	power and wiring and interval and array and (shielding layer) and window near light and "257"/$.ccls.	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:38
S23	6	power and wiring and interval and array and (shielding layer) and window near light and "250"/$.ccls.	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 15:38

S24	5	S22 and S23	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:39
S25	2	power with contact and wiring and interval and array and (shielding layer) and window near light	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:54
S26	49	power same contact with wiring with interval	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:55
S27	0	power same contact with wiring with interval and contact with (shield$3 layer) with window	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:55
S28	0	power same contact with wiring with interval and contact same (shield$3 layer) same window	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:56
S29	49	power same contacts with wiring with interval	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:56
S30	0	power same contacts with wiring with interval and "358"/$.ccls.	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 15:56
S31	12	power same contacts with wiring with interval and "257"/$.ccls.	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 16:18
S32	1270	color adj picture adj elements	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 16:19
S33	123	color adj picture adj elements same layer	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 16:20
S34	62	color adj picture adj elements same layer same filter	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 16:20
S35	1	color adj picture adj elements same layer same filter same contacts	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/03/17 16:21

S36	32	color adj picture adj elements and layer same filter same contacts	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 16:29
S37	62	color adj picture adj elements same layer same filter	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 16:31
S38	0	color adj picture adj elements same layer same filter and well with contact	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 16:30
S39	1	color adj picture adj elements same layer same filter and well same contact	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 16:31
S40	0	color adj picture adj elements same layer same filter and common adj well	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2004/03/17 16:31
S41	2	"6051857".pn. and semiconductor	USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/05/19 18:22